





100V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{DS} (V) | 100 |
|----------------------|-----|
| $R_{DS(ON)}(\Omega)$ | 10 |

Description and Applications

This MOSFET utilises a structure that combines low input capacitance with relatively low on-resistance and has an intrinsically higher pulse current handling capability in linear mode than a comparable trench technology structure. This MOSFET is suitable for general purpose applications.

- General purpose 100V FET
- Power management
- Disconnect switches
- Telecoms
- Complementary Type ZVP3310F

Features and Benefits

- · High pulse current handling in linear mode
- Low input capacitance
- Fast switching speed
- Lead Free By Design/RoHS Compliant (Note 1)

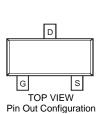
Mechanical Data

- Case: SOT-23
- Case Material: UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

SOT-23



TOP VIEW



Gate Source
Equivalent Circuit

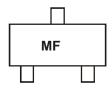
Ordering Information (Note 2)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel | |
|------------|---------|--------------------|-----------------|-------------------|--|
| ZVN3310FTA | MF | 7 | 8 | 3000 | |

Notes:

- 1. No purposefully added lead.
- 2. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



MF = Product Type Marking Code





Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Units | |
|--------------------------|-----------------|-------|-------|--|
| Drain-Source Voltage | V_{DSS} | 100 | V | |
| Gate-Source Voltage | V_{GSS} | ±20 | V | |
| Continuous Drain Current | I _D | 100 | mA | |
| Pulsed Drain Current | I _{DM} | 2 | А | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Power Dissipation @T _A = 25°C | P_{D} | 330 | mW |
| Operating and Storage Temperature Range | $T_{J_1}T_{STG}$ | -55 to +150 | °C |

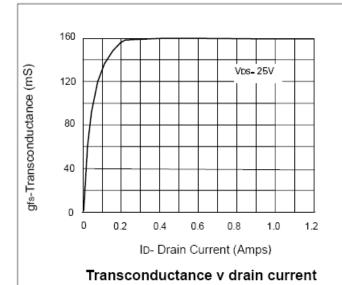
Electrical Characteristics @T_A = 25°C unless otherwise specified

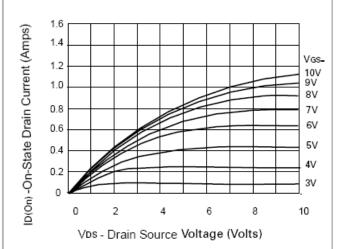
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | | |
|--|----------------------|-----|-----|---------|------|---|--|--|
| OFF CHARACTERISTICS | | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 100 | _ | | V | $I_D = 1 \text{mA}, V_{GS} = 0 \text{V}$ | | |
| Zero Gate Voltage Drain Current $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$ (Note 4) | I _{DSS} | _ | _ | 1 50 | μА | $V_{DS} = 100V, V_{GS} = 0V$ $V_{DS} = 80V, V_{GS} = 0V$ | | |
| Gate-Source Leakage | I_{GSS} | _ | _ | 20 | nA | $V_{GS} = \pm 20V$, $V_{DS} = 0V$ | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.8 | _ | 2.4 | V | $V_{DS} = V_{GS}$, $I_D = 1mA$ | | |
| ON CHARACTERISTICS (Note 3) | | | | | | | | |
| On-State Drain Current | I _{D (ON)} | 500 | _ | _ | mA | $V_{DS} = 25V, V_{GS} = 10V$ | | |
| Static Drain-Source On-Resistance | R _{DS} (ON) | _ | _ | 10 | Ω | $V_{GS} = 10V, I_D = 500mA$ | | |
| DYNAMIC CHARACTERISTICS (Note 4) | | | | | | | | |
| Forward Transconductance (Note 3) | g_{fs} | 100 | _ | _ | mS | $V_{DS} = 25V, I_D = 500mA$ | | |
| Input Capacitance | C _{iss} | _ | _ | 40 | | V 05V V 0V | | |
| Output Capacitance | Coss | _ | _ | 15 | pF | $V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz | | |
| Reverse Transfer Capacitance | Crss | _ | _ | 5 | | I = 1.0IVID2 | | |
| Turn-On Delay Time (Note 5) | t _{D(on)} | _ | 3 | 5 | | | | |
| Turn-On Rise Time (Note 5) | t _r | _ | 5 | 7 | | $V_{DD} \approx 25V$, $I_D = 500$ mA | | |
| Turn-Off Delay Time (Note 5) | t _{D(off)} | _ | 4 | 6 | ns | | | |
| Turn-Off Fall Time (Note 5) | t _f | _ | 5 | 7 | | | | |

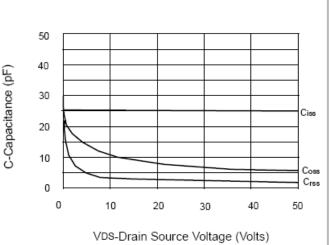
Notes:

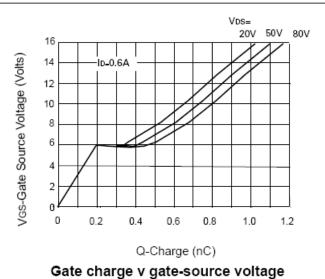
- 3. Measured under pulsed conditions. Width = $300\mu s$. Duty cycle $\leq 2\%$
- Sample test.
- 5. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.





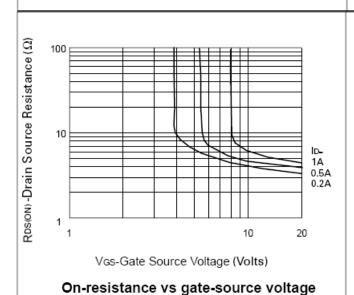


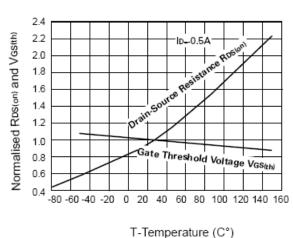




Saturation Characteristics

Capacitance v drain-source voltage

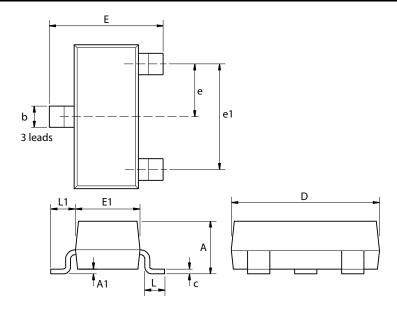




Normalised Rds(on) and Vgs(th) vs Temperature



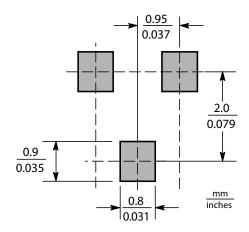
Package Outline Dimensions



| Dim. | Millimeters | | Inches | | Dim. | Millimeters | | Inches | |
|------|-------------|------|--------|-------|------|-------------|------|-----------|--------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| Α | - | 1.12 | - | 0.044 | e1 | 1.90 | NOM | 0.075 NOM | |
| A1 | 0.01 | 0.10 | 0.0004 | 0.004 | Е | 2.10 | 2.64 | 0.083 | 0.104 |
| b | 0.30 | 0.50 | 0.012 | 0.020 | E1 | 1.20 | 1.40 | 0.047 | 0.055 |
| С | 0.085 | 0.20 | 0.003 | 0.008 | L | 0.25 | 0.60 | 0.0098 | 0.0236 |
| D | 2.80 | 3.04 | 0.110 | 0.120 | L1 | 0.45 | 0.62 | 0.018 | 0.024 |
| е | 0.95 NOM | | 0.037 | NOM | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Suggested Pad Layout







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